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NCE6030K

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6030K uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

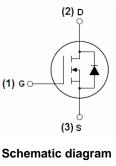
General Features

- V_{DS} =60V,I_D =30A $R_{DS(ON)}$ <27m Ω @ V_{GS} =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED! 100% AVds TESTED!





Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6030K	NCE6030K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	30	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	20	Α
Pulsed Drain Current	I _{DM}	74	Α
Maximum Power Dissipation	P _D	50	W
Derating factor		0.33	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	144	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$

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Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	3	°C/W
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Electrical Characteristics (T_c=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA 60		-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.4	1.8	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	23	27	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	-	30	-	S
Dynamic Characteristics (Note4)	<u>.</u>					
Input Capacitance	C _{lss}	\/ 00\/\/ 0\/	-	1900	-	PF
Output Capacitance	Coss	V_{DS} =30V, V_{GS} =0V,	-	130	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	95	-	PF
Switching Characteristics (Note 4)	<u> </u>		•			
Turn-on Delay Time	t _{d(on)}		-	5	-	nS
Turn-on Rise Time	t _r	V_{DS} =30V, R_L =1.5 Ω	-	2.6	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =3 Ω	-	16.1	-	nS
Turn-Off Fall Time	t _f		-	2.3	-	nS
Total Gate Charge	Qg	V -20VI -20A	-	30		nC
Gate-Source Charge	Q _{gs}	$V_{DS}=30V,I_{D}=20A,$ $V_{GS}=10V$	-	4.5		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	7.5		nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =30A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	30	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =20A	-	35	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	53	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

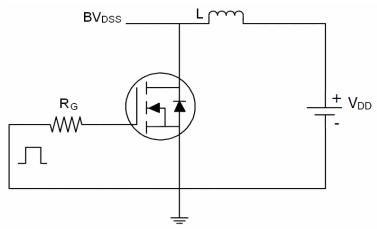
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition:Tj=25 $^{\circ}$ C,VDD=30V,VG=10V,L=0.5mH,Rg=25 Ω

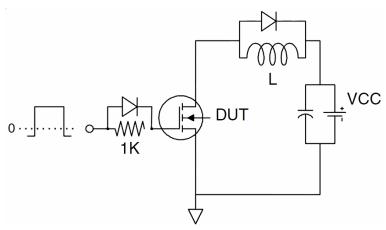
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Test Circuit

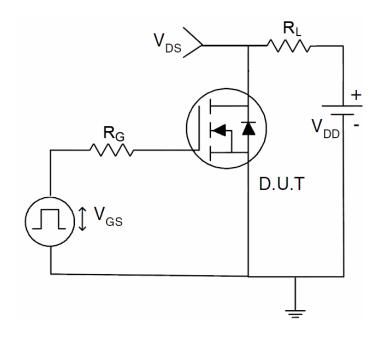
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit







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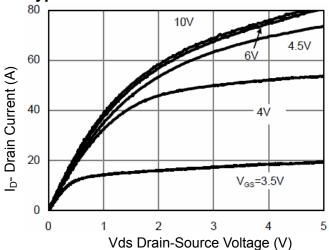


Figure 1 Output Characteristics

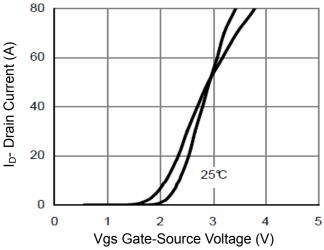


Figure 2 Transfer Characteristics

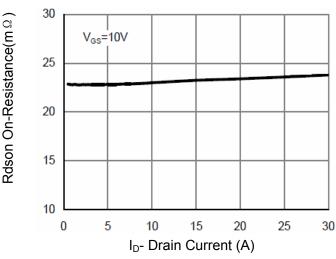


Figure 3 Rdson- Drain Current

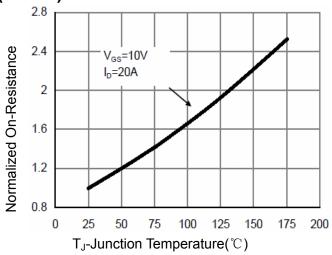


Figure 4 Rdson-Junction Temperature

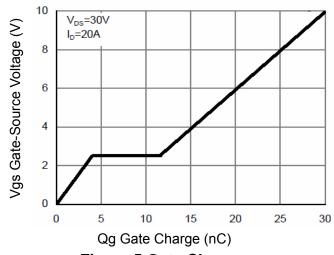


Figure 5 Gate Charge

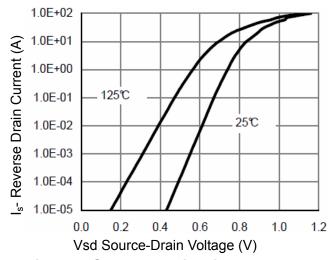


Figure 6 Source- Drain Diode Forward



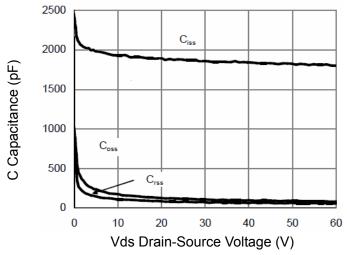


Figure 7 Capacitance vs Vds

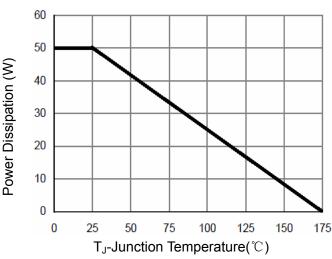


Figure 9 Power De-rating

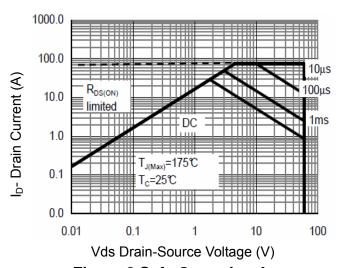


Figure 8 Safe Operation Area

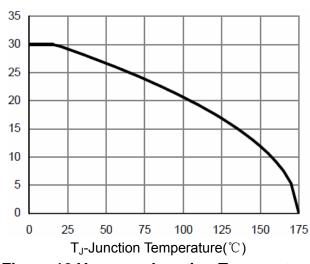


Figure 10 V_{GS(th)} vs Junction Temperature

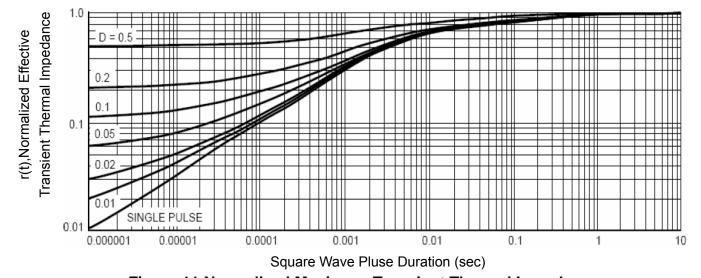


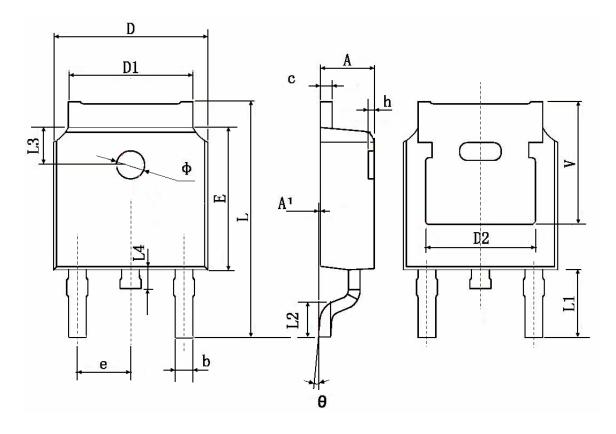
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	4.830 TYP. 0.190 TY			
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	TYP.	0.114	ГҮР.	
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063	TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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